

Messrs. <u>LITE-ON Technology Corp.</u>

# **Approval Sheet for Product Specification**

Issued Date: 15/Nov/2004

Product Description :	BlueModule™
Customer Part Number :	
Murata Part Number :	LBMA477BK2-064
Date :	
Company :	
Dept. :	
Бори.	
Approved by	
Signature :	
Type :	

The duplicate of this specification shall be returned to us with your authorised signiture. Unless it reaches us by 27/December/2004, it shall be mutually understood that this specification has been duly approved by you.

Prepared by	
Keisuke Katabuchi	(signature)
Keisuke Katabuchi	(type)
Approved by	(signature)
Norio Makajima Manager	(type)
Product Engineering Section I	

Multilayer Products Department
Component Division III
Murata Manufacturing Co., Ltd.



# 1. Scope

This specification is applied to the Bluetooth HCI module (Blue  $Module^{TM}$ ).

# 2. Part Number

Production Part Number	LBMA477BK2-064

# 3. Rating

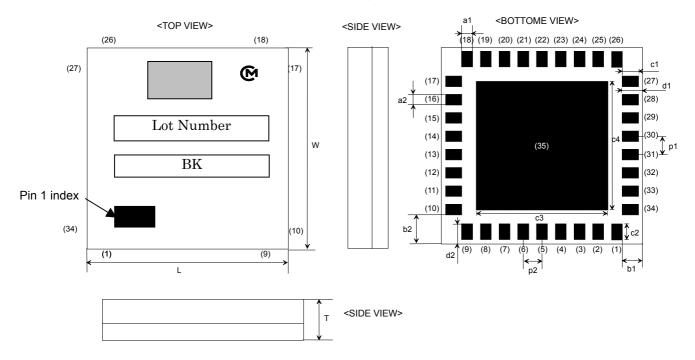
# Ratings

		Min	Max	Unit
	Operating Temperature	-20	+70	deg.C
	Storage Temperature	-40	+85	deg.C
	Terminal Name	Min	Max	Unit
Supply Voltage	BTRF_REG		2.2	V
	BTL_REG		2.2	V
	V_I_O		4.1	V
	Input Terminal Voltage	Vss-0.3	VDD+0.3	V

4. Weight (Nominal) 0.3g



# 5. CONSTRUCTION, DIMENSIONS and Terminal Configurations



Mark	Dimension	Mark	Dimension	Mark	Dimension
L	7.5±0.2	W	7.5±0.2	Т	1.4 max
a1	$0.4 \pm 0.2$	a2	0.4±0.2	b1	0.75±0.2
b2	1.1±0.2	c1	0.6±0.2	c2	0.6±0.2
с3	4.9±0.2	c4	4.9±0.2	d1	0.75±0.2
d2	0.75±0.2	p1	0.7±0.2	p2	0.7±0.2

(Unit: mm)



# **Terminal Configurations**

Terminal	Terminal Name	Pin Type	Description
No.			
(1)	GROUND	I	-
(2)	NC	-	-
(3)	NC	-	-
(4)	NC	-	-
(5)	BLUE_TX	I	<uart_rxd> UART data input active high</uart_rxd>
(6)	REG_CTRL	I	Internal 1.8V regulator enable signal
(7)	EEPROM_CLK	0	Clock interface to an optional serial EEPROM
(8)	NC	-	
(9)	BLUE_HOST_WAKE	0	HOST_WAKE signal for power control
(10)	V_I_O	I	-
(11)	BLUE_WAKE	I	Active high or active low BT_WAKE signal for powe control
(12)	LPO_IN	I	32.768KHz digital clock input
(13)	BLUE_CLK_EN	0	-
(14)	GROUND	I	-
(15)	XTAL_OUT	0	Crystal Oscillator output
(16)	XTAL IN	I	Crystal or frequency reference input
(17)	GROUND	I	-
(18)	TM0	I	Test Mode 0
(19)	TM1 2	I	Test mode 1 and 2
(20)	TM3	I	Test mode 3
(21)	BTRF_REG	I	-
(22)	RESET N	I	Active LOW system reset
(23)	TX_PU_TDD_N	0	Complement of TX_PU_TDD
(24)	GROUND	I	
(25)	ANTENNA MATCH	I/O	<ant> RF input/output</ant>
(26)	GROUND	I	-
(27)	ASAP_CLK	I/O	<pcm_clk> Synchronous data clock</pcm_clk>
(28)	ASAP FS	I/O	<pcm_sync> Synchronous data sync</pcm_sync>
(29)	BLUE_CTS	I	<ul> <li><uart_cts> UART clear to send active low</uart_cts></li> </ul>
(30)	ASAP RX	0	<pcm_out> Synchronous data output</pcm_out>
(31)	BLUE RTS	0	<ul> <li><uart_rts> UART request to send</uart_rts></li> </ul>
. ,	_	Ŭ	active low
(32)	ASAP_TX	I	<pcm_in> Synchronous data input</pcm_in>
(33)	BLUE_RX	0	<uart_txd> UART data output active high</uart_txd>
(34)	BTL_REG	I	-
(35)	GROUND	I	-



# 6. Electrical Characteristics

6-1 Operating Conditions

	Min	Тур	Max	Unit
Operating Temperature	-20	+25	+70	deg.C
Supply Voltage				
BTRF_REG, BTL_REG	1.71	1.8	1.98	V
V_I_O	1.71	2.8	3.63	V

## 6-2-1 Characteristics

+25degC,BTRF REG/BTL REG=1.8V, VIO=2.75V

Bluetooth specification	+25degC,BTRF_REG/BTL_REG=1.8V, VIO=2.7	5V				
Channel spacing         1MHz           Number of RF channel         79           Power class           Operation mode(Rx/Tx)         Time division multiplex either transmit or receive Frequency hopping after one Rx/Tx cycle           Items         Min         Typ         Max         Unit           1. Current Consumption RF Register x57=xC6         Min         Typ         Max         Unit           1. SULJ_O REG_IDC_max         DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle         75         mA           1.3 V_LJ_O REG_IDC_max         DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle         10         mA           2.0utput Power         -4         4         dBm           3.Frequency range (Rx/Tx)         2400.5~2483.5MHz           4. 220dB bandwidth         1         MHz           5.Adjacent Channel Power '¹         1         MHz           5.1 [M-N]=2         2         -21         dBm           5.2 [M-N]≥3         -41         dBm           6.2 [Modulation δ f1avg         145         173         kHz           6.3 Modulation δ f2rmax         125         kHz           8.1 Islot         -25         25         kHz           8.2 3slot         -40	1001110	Contents				
Number of RF channel   79   2						
Power class         2           Operation mode(Rx/Tx)         Time division multiplex either transmit or receive Frequency hopping after one Rx/Tx cycle           Items         Min         Typ         Max         Unit           1. Unit         Min         Typ         Max         Unit           1. BTRF_REG_IDC_max DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle         75         mA           1.3 Y 1_0 REG_IDC_max DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle         10         mA           2.Output Power         -4         4         dBm           3.Frequency range (Rx/Tx)         2400.5~2483.5MHz         4.200.5~2483.5MHz           420dB bandwidth         1         MHz         5.4 (Bm           5.2 [M-N] = 2         -21         dBm           5.2 [M-N] ≥ 3         -41         dBm           6.1 Modulation δ flavg         145         173         kHz           6.2 Modulation δ f2xmx         125         kHz           6.3 Modulation δ f2xmx         125         kHz           8.Carrier Frequency Tolerance         -45         45         kHz           8.Carrier Frequency Tolerance         -45         40         kHz           8.2 3slot         -40         40         kHz           <			1MHz			
Time division multiplex either transmit or receive Frequency hopping after one Rx/Tx cycle						
Items						
Items	Operation mode(Rx/Tx)					
1. Current Consumption RF Register x57=xC6  1.1 BTRF_REG_IDC_max DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle  1.3 V_I_O_REG_IDC_max DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle  -TX characteristics- Min Typ Max Unit 2. Output Power -4 4 4 dBm 3. Frequency range (Rx/Tx)  420dB bandwidth 1 1 MHz  5. Adjacent Channel Power '1  5.1 [M-N] = 2 -21 dBm 6. Modulation characteristics 6.1 Modulation δ f1avg 145 173 kHz 6.2 Modulation δ f2wax 125 kHz 6.3 Modulation δ f2wax 125 kHz 6.3 Modulation δ f2way δ f1avg 0.85  7. Initial Carrier Frequency Tolerance -45 45 kHz 8.1 Islot -25 25 kHz 8.2 3slot -40 40 kHz 8.3 Solot -40 40 kHz 8.4 Maximum drift rate -20 20 kHz/50 μ s 9. Out-of-Band Spurious Emissions 9.1 30-1000MHz (Operation Mode) -36 dBm 9.2 1000-12750MHz (Operation Mode) -30 dBm 9.3 1800-1900MHz (Operation Mode) -75 dBm						
RF Register x57=xC6       1.1 BTRF_REG_IDC_max         DH5; 100% slot utilization;       75         50% Rx/Tx slot duty cycle       10         1.3 V_L_O_REG_IDC_max       10         DH5; 100% slot utilization;       10         50% Rx/Tx slot duty cycle       10         -TX characteristics-       Min       Typ       Max         2.Output Power       -4       4       dBm         3.Frequency range (Rx/Tx)       2400.5~2483.5MHz         420dB bandwidth       1       MHz         5.Adjacent Channel Power '1       1       MHz         5.1 [M-N]=2       -21       dBm         5.2 [M-N]≥3       -41       dBm         6.Modulation characteristics       -41       dBm         6.1 Modulation δ f1avg       145       173       kHz         6.2 Modulation δ f2avg/ δ f1avg       1.85       KHz       45       kHz         6.3 Modulation δ f2avg/ δ f1avg       0.85       -45       kHz         7.Initial Carrier Frequency Drift       -45       45       kHz         8.1 1slot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.4 Maximum drift rate       -20       20		Min	Тур	Max	Unit	
1.1 BTRF_REG_IDC_max       75       mA         DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle       10       mA         1.3 V_LO_REG_IDC_max       10       mA         DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle       10       mA         -TX characteristics-       Min       Typ       Max       Unit         2.Output Power       -4       4       dBm         3.Frequency range (Rx/Tx)       2400.5~2483.5MHz       420dB bandwidth       1       MHz         5.2 [M-N]≥2       -21       dBm       dBm       5.2 [M-N]≥3       -41       dBm         6.Modulation characteristics       -21       dBm       dBm       6.Modulation characteristics       -41       dBm         6.1 Modulation δ f1avg       145       173       kHz       kHz       6.2       Modulation δ f2avg/ δ f1avg       0.85       -7.Initial Carrier Frequency Tolerance       -45       45       kHz       8.Carrier Frequency Tolerance       -45       45       kHz       8.2       3slot       -40       40       kHz       8.3       5slot       -40       40       kHz       8.3       5slot       -40       40       kHz/50 μs       9.Out-of-Band Spurious Emissions       9.1       30-1000MHz (Operation Mode)       -36 <td></td> <td></td> <td></td> <td></td> <td></td>						
DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle         75         mA           1.3 V_I_O_REG_IDC_max DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle         10         mA           -TX characteristics-         Min         Typ         Max         Unit           2.Output Power         -4         4         dBm           3.Frequency range (Rx/Tx)         2400.5~2483.5MHz         420dB bandwidth         1         MHz           5.Adjacent Channel Power '1         1         MHz         5.Adjacent Channel Power '1         -21         dBm           5.1 [M-N]=2         -21         dBm         6.Modulation of 12mx         -41         dBm           6.1 Modulation of f2max         145         173         kHz         6.2         Modulation of f2max         125         kHz         kHz           6.3 Modulation of f2avg/ δ f1avg         0.85         -45         kHz         8.Carrier Frequency Drift         -25         25         kHz           8.1 1slot         -25         25         kHz         8.3 slot         40         40         kHz           8.4 Maximum drift rate         -20         20         kHz/50 μ s         9.Out-of-Band Spurious Emissions         -36         dBm         9.2         1000-12750MHz (Operation Mode)         -30 <td></td> <td></td> <td></td> <td></td> <td></td>						
50% Rx/Tx slot duty cycle       1.3 V_L O_REG_IDC_max         DH5; 100% slot utilization;       10         50% Rx/Tx slot duty cycle       10         -TX characteristics-       Min       Typ       Max       Unit         2.Output Power       -4       4       dBm         3.Frequency range (Rx/Tx)       2400.5~2483.5MHz         420dB bandwidth       1       MHz         5.Adjacent Channel Power ¹¹       -21       dBm         5.1 [M-N]=2       -21       dBm         5.2 [M-N]≥3       -41       dBm         6.Modulation characteristics       -41       dBm         6.1 Modulation δf1avg       145       173       kHz         6.2 Modulation δf2anax       125       kHz       kHz         6.3 Modulation δf2avg/ δf1avg       0.85       -45       kHz         7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 Islot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μs         9.Out-of-Band Spurious Emissions       -3						
1.3 V_I_O_REG_IDC_max DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle       10       mA         -TX characteristics-       Min       Typ       Max       Unit         2.Output Power       -4       4       dBm         3.Frequency range (Rx/Tx)       2400.5~2483.5MHz         420dB bandwidth       1       MHz         5.Adjacent Channel Power '1       -21       dBm         5.1 [M-N]=2       -21       dBm         5.2 [M-N]≥3       -41       dBm         6.Modulation characteristics       -41       dBm         6.1 Modulation δ f1avg       145       173       kHz         6.2 Modulation δ f2max       125       kHz         6.3 Modulation δ f2avg/ δ f1avg       0.85       -40       kHz         7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 Islot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36				75	mA	
DH5; 100% slot utilization; 50% Rx/Tx slot duty cycle						
50% Rx/Tx slot duty cycle         Min         Typ         Max         Unit           2.Output Power         -4         4         dBm           3.Frequency range (Rx/Tx)         2400.5~2483.5MHz           420dB bandwidth         1         MHz           5.Adjacent Channel Power ¹¹         -21         dBm           5.1 [M-N]=2         -21         dBm           5.2 [M-N]≧3         -41         dBm           6.Modulation characteristics         -41         dBm           6.1 Modulation δ f1avg         145         173         kHz           6.2 Modulation δ f2max         125         kHz           6.3 Modulation δ f2avg/ δ f1avg         0.85				40	Л	
-TX characteristics-  2.Output Power  3.Frequency range (Rx/Tx)  420dB bandwidth  5.Adjacent Channel Power '1  5.1 [M-N]=2  5.2 [M-N]≥3  6.Modulation characteristics  6.1 Modulation δ f1avg  6.2 Modulation δ f2max  6.3 Modulation δ f2max  6.3 Modulation δ f2avg/ δ f1avg  7.Initial Carrier Frequency Tolerance  8.1 1slot  8.2 3slot  8.4 Maximum drift rate  9.0 20  9.Out-of-Band Spurious Emissions  9.1 30-1000MHz (Operation Mode)  9.3 1800-1900MHz (Operation Mode)  9.4 2110-2170MHz (Operation Mode)  9.4 2110-2170MHz (Operation Mode)  9.4 2110-2170MHz (Operation Mode)  -40  -40  -40  -40  -40  -47  -47  -48  -49  -47  -40  -47  -47  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -48  -47  -47	· · · · · · · · · · · · · · · · · · ·			10	mA	
2.Output Power       -4       4       dBm         3.Frequency range (Rx/Tx)       2400.5~2483.5MHz         420dB bandwidth       1       MHz         5.Adjacent Channel Power '1       -21       dBm         5.1 [M-N]=2       -21       dBm         5.2 [M-N]≥3       -41       dBm         6.Modulation characteristics       -41       dBm         6.1 Modulation δ f1avg       145       173       kHz         6.2 Modulation δ f2max       125       kHz         6.3 Modulation δ f2avg/ δ f1avg       0.85       -45       kHz         7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 Islot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -30       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm		Min	Tura	Mov	Linit	
3.Frequency range (Rx/Tx)  420dB bandwidth  5.Adjacent Channel Power *1  5.1 [M-N]=2  5.2 [M-N]≥3  6.Modulation characteristics  6.1 Modulation δ f1avg  6.2 Modulation δ f2max  6.3 Modulation δ f2avg/ δ f1avg  7.Initial Carrier Frequency Tolerance  8.1 1slot  8.1 1slot  8.2 3slot  8.4 Maximum drift rate  9.Out-of-Band Spurious Emissions  9.1 30-1000MHz (Operation Mode)  9.3 1800-1900MHz (Operation Mode)  9.4 2110-2170MHz (Operation Mode)  9.75 dBm			тур			
420dB bandwidth       1       MHz         5.Adjacent Channel Power '1       -21       dBm         5.1 [M-N]=2       -21       dBm         5.2 [M-N]≧3       -41       dBm         6.Modulation characteristics       -41       dBm         6.1 Modulation δ f1avg       145       173       kHz         6.2 Modulation δ f2max       125       kHz         6.3 Modulation δ f2avg/ δ f1avg       0.85       -         7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 1slot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.3 5slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μs         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm		<u> </u>			UBIII	
5.Adjacent Channel Power *1       5.1 [M-N]=2       -21       dBm         5.2 [M-N]≥3       -41       dBm         6.Modulation characteristics       -41       dBm         6.1 Modulation δ f1 avg       145       173       kHz         6.2 Modulation δ f2 avg/ δ f1 avg       125       kHz         6.3 Modulation δ f2 avg/ δ f1 avg       0.85       -45       kHz         7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 1slot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.3 1800-1900MHz (Operation Mode)       -30       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm			2400.5 <b>~</b> 2	1	N 41 1	
5.1 [M-N]=2       -21       dBm         5.2 [M-N]≥3       -41       dBm         6.Modulation characteristics       -41       dBm         6.1 Modulation δ f1avg       145       173       kHz         6.2 Modulation δ f2max       125       kHz         6.3 Modulation δ f2avg/ δ f1avg       0.85       -45       kHz         7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 1slot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.3 5slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm				1	MHZ	
5.2 [M-N]≥3 6.Modulation characteristics 6.1 Modulation δ f1avg 6.2 Modulation δ f2max 6.3 Modulation δ f2avg/ δ f1avg 7.Initial Carrier Frequency Tolerance 8.Carrier Frequency Drift 8.1 1slot 8.1 1slot 8.2 3slot 4.40 8.3 5slot 4.40 8.4 Maximum drift rate 9.Out-of-Band Spurious Emissions 9.1 30-1000MHz (Operation Mode) 9.3 1800-1900MHz (Operation Mode) 9.4 2110-2170MHz (Operation Mode) 9.4 2110-2170MHz (Operation Mode) 9.4 2110-2170MHz (Operation Mode)  -41 dBm 6.Modulation δ f2avg/ δ f1avg 125 8.Hz 45 8.Hz 45 8.Hz 45 8.Hz 46 8.Hz 40 8.Hz 40 8.Hz 8.A 6Bm 9.2 1000-12750MHz (Operation Mode) 9.3 1800-1900MHz(Operation Mode) 9.4 2110-2170MHz (Operation Mode) 9.5 dBm						
6.Modulation characteristics 6.1 Modulation $\delta$ f1avg 145 173 kHz 6.2 Modulation $\delta$ f2max 125 8.3 Modulation $\delta$ f2avg/ $\delta$ f1avg 7.Initial Carrier Frequency Tolerance 8.Carrier Frequency Drift 8.1 1slot 8.2 3slot 40 40 kHz 8.3 5slot 40 40 kHz 8.4 Maximum drift rate 9.Out-of-Band Spurious Emissions 9.1 30-1000MHz (Operation Mode) 9.3 1800-1900MHz (Operation Mode) 9.4 2110-2170MHz (Operation Mode) 9.4 2110-2170MHz (Operation Mode) 9.4 2110-2170MHz (Operation Mode) 9.75 dBm						
6.1Modulation $\delta$ f1avg145173kHz6.2Modulation $\delta$ f2amax125kHz6.3Modulation $\delta$ f2avg/ $\delta$ f1avg0.857.Initial Carrier Frequency Tolerance-4545kHz8.Carrier Frequency Drift2525kHz8.11slot-2525kHz8.23slot-4040kHz8.35slot-4040kHz8.4Maximum drift rate-2020kHz/50 $\mu$ s9.Out-of-Band Spurious Emissions9.130-1000MHz (Operation Mode)-36dBm9.21000-12750MHz (Operation Mode)-30dBm9.31800-1900MHz(Operation Mode)-47dBm9.42110-2170MHz (Operation Mode)-75dBm	- L 1—-			-41	dBm	
6.2 Modulation δ f2max       125       kHz         6.3 Modulation δ f2avg/ δ f1avg       0.85	6.Modulation characteristics					
6.3 Modulation δ f2avg/ δ f1avg       0.85         7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 Islot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.3 5slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -30       dBm         9.3 1800-1900MHz (Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm	6.1 Modulation δ f1avg	145		173	kHz	
7.Initial Carrier Frequency Tolerance -45	6.2 Modulation δ f2max	125			kHz	
7.Initial Carrier Frequency Tolerance       -45       45       kHz         8.Carrier Frequency Drift       -25       25       kHz         8.1 Islot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.3 5slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -30       dBm         9.3 1800-1900MHz(Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm	6.3 Modulation δ f2avg/ δ f1avg	0.85				
8.Carrier Frequency Drift       25       25       kHz         8.1 Islot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.3 5slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -30       dBm         9.3 1800-1900MHz(Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm		-45		45	kHz	
8.1 1slot       -25       25       kHz         8.2 3slot       -40       40       kHz         8.3 5slot       -40       40       kHz         8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -30       dBm         9.3 1800-1900MHz(Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm						
8.3       5slot       -40       40       kHz         8.4       Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       9.1       30-1000MHz (Operation Mode)       -36       dBm         9.2       1000-12750MHz (Operation Mode)       -30       dBm         9.3       1800-1900MHz (Operation Mode)       -47       dBm         9.4       2110-2170MHz (Operation Mode)       -75       dBm		-25		25	kHz	
8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -30       dBm         9.3 1800-1900MHz(Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm	8.2 3slot	-40		40	kHz	
8.4 Maximum drift rate       -20       20       kHz/50 μ s         9.Out-of-Band Spurious Emissions       -36       dBm         9.1 30-1000MHz (Operation Mode)       -36       dBm         9.2 1000-12750MHz (Operation Mode)       -30       dBm         9.3 1800-1900MHz(Operation Mode)       -47       dBm         9.4 2110-2170MHz (Operation Mode)       -75       dBm	8.3 5slot	-40		40	kHz	
9.Out-of-Band Spurious Emissions       -36       dBm         9.1       30-1000MHz (Operation Mode)       -36       dBm         9.2       1000-12750MHz (Operation Mode)       -30       dBm         9.3       1800-1900MHz(Operation Mode)       -47       dBm         9.4       2110-2170MHz (Operation Mode)       -75       dBm	8.4 Maximum drift rate	-20		20	kHz/50 μ s	
9.1       30-1000MHz (Operation Mode)       -36       dBm         9.2       1000-12750MHz (Operation Mode)       -30       dBm         9.3       1800-1900MHz (Operation Mode)       -47       dBm         9.4       2110-2170MHz (Operation Mode)       -75       dBm	9.Out-of-Band Spurious Emissions				, , , , ,	
9.2       1000-12750MHz (Operation Mode)       -30       dBm         9.3       1800-1900MHz(Operation Mode)       -47       dBm         9.4       2110-2170MHz (Operation Mode)       -75       dBm				-36	dBm	
9.3       1800-1900MHz(Operation Mode)       -47       dBm         9.4       2110-2170MHz (Operation Mode)       -75       dBm	\ \ \					
9.4 2110-2170MHz (Operation Mode) -75 dBm						
	9.5 5150-5300MHz (Operation Mode)				dBm	



-RX characteristics-	min	typ	max	unit
10.Sensitivity (BER≦0.1%)				
10.1 2402MHz			-79	dBm
10.2 2441MHz			-79	dBm
10.3 2480MHz			-79	dBm
11.C/I Performance (BER≦0.1%) *2				
11.1 co-channel ratio (-60dBm input)			11	dBm
11.2 1MHz ratio (-60dBm input)			0	dBm
11.3 2MHz ratio (-60dBm input)			-30	dBm
11.4 3MHz ratio (-67dBm input)			-40	dBm
11.5 image ratio (-67dBm input)			-9	dBm
11.6 image +/- 1MHz ratio (-67dBm input)			-20	dBm
12.Blocking performance(BER<0.1%) *3				
12.1 30MHz-2000MHz	-10			dBm
12.2 2000MHz-2400MHz	-27			dBm
12.3 2500MHz-3000MHz	-27			dBm
12.4 3000MHz-12750MHz	-10			dBm
13.Intermodulation performance (BER≦0.1%, -64dBm input)	-35			dBm
14.Maximum Input Level	-20			dBm

<sup>4.</sup>Maximum Input Level | -20

1 Up to three sprious responses within Bluetooth limits are allowed.

2 Up to five sprious responses within Bluetooth limits are allowed.

3 Up to twenty-four sprious responses within Bluetooth limits are allowed.



6-2-2. Extreme condition: -20 to +70degC, BTRF REG/BTL REG=1.71-1.98V, VIO=1.71-3.63V

Items	Min	Typ	Max	Unit
1.Current Consumption		1 171		5.110
RF Register x57=xC6				
1.1 BTRF_REG_IDC_max				
DH5; 100% slot utilization;			80	mA
50% Rx/Tx slot duty cycle				
1.3 V_I_O_REG_IDC_max				
DH5; 100% slot utilization;			12	mA
50% Rx/Tx slot duty cycle				
-TX characteristics-	Min	Тур	Max	Unit
2.Output Power	-6		+6	dBm
3.Frequency range (Rx/Tx)		2400.5~2	2483.5MHz	
420dB bandwidth			1	MHz
5.Adjacent Channel Power *1				
5.1 [M-N]=2			-20	dBm
5.2 [M-N]≧3			-40	dBm
6.Modulation characteristics				
6.1 Modulation δ f1avg	145		175	kHz
6.2 Modulation δ f2max	115			kHz
6.3 Modulation δ f2avg/ δ f1avg	8.0			
7.Initial Carrier Frequency Tolerance	-75		75	kHz
8.Carrier Frequency Drift				
8.1 1slot	-25		25	kHz
8.2 3slot	-40		40	kHz
8.3 5slot	-40		40	kHz
8.4 Maximum drift rate	-20		20	kHz/50 μ s
9.Out-of-Band Spurious Emissions				
9.1 30-1000MHz (Operation Mode)	-36			dBm
9.2 1000-12750MHz (Operation Mode)	-30			dBm
9.3 1800-1900MHz(Operation Mode)	-47			dBm
9.4 2110-2170MHz (Operation Mode)	-65			dBm
9.5 5150-5300MHz (Operation Mode)	-47			dBm

-RX characteristics-	min	typ	max	unit
10.Sensitivity (BER≦0.1%)				
10.1 2402MHz			-77	dBm
10.2 2441MHz			-77	dBm
10.3 2480MHz			-77	dBm

<sup>\*1</sup> Up to three spurious responses within Bluetooth limits are allowed.

### Note

The above mentioned values have been obtained according to our own measuring methods (testing jig Fig.1) and may very depend on the circuit, in which the component is actually incorporated. Therefore, you are kindly requested to test the performance of the component actually in your set.



# 7. Other Specification and Methods

1 Vibratio	on Annon	Specifica		
Resista	ance	rance No severe damage		Solder specimens on the testing jig shown in appended Fig.3 by an solder. The soldering shall be done either by iron or reflow and be
	Electri Specifi s		ons listed in	conducted with care so that the soldering is uniform and free of defect such as by heat shock.  Frequency: 10 to 2000 by 10 Hz Acceleration: 196 m/s² Direction: X,Y,Z 3axes Period: 2 h on each direction (Total 6 h.)
2 Shock	Appea	rance No severe damage	es	Solder specimens on the testing jig shown in appended Fig.3 by an solder. The soldering shall be done either by iron or reflow and be
	Electri Specifi s		ons listed in	conducted with care so that the soldering is uniform and free of defect such as by heat shock.  Pulse Wave: Sine Half Wave Acceleration: 30000 m/s² (Peak) Period: 0.3 ms. Cycle: 10 times
3 Deflect	tion	No damage with 1r	nm deflection	Solder specimens on the testing jig shown in appended Fig.3 by an solder. The soldering shall be done either by iron or reflow and be conducted with care so that the soldering is uniform and free of defect such as by heat shock.
	ing strength Strength)	9.8 N Minimum	Pushin	Solder specimens on the testing jig shown in appended Fig.3 by an solder. As shown below, apply pushing force at 0.5 mm/s until electrode pads are pealed off or ceramics are broken. Pushing force is applied as show below.  Specimen  Direction  Jig
				\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
5 Solder	ability of Termin	ation 75% of the termin soldered evenly an		Immerse specimens first a ethanol solution of rosin (25% rosin in weight proportion), then in an solder solution for 2+/-0.5 s at 230+/-5 deg.C.  Preheat : 100 to 120 deg.C, 60 s  Solder Paste : Eutectic Solder  Flux : Solution of ethanol and rosin (25% rosin in weight proportion)
6 Resista to Sol Heat				Preheat Temperature : 150 +/-10 deg.C Preheat Period : 60s Peak Temperature : 230+/-5 deg.C
(Reflov			oiis iistea in	Peak Temperature . 23047-5 deg.C Peak Temp. Period : 10 s Specimens are soldered once with the above condition, then kept in room condition for 24 h before measurements.
No.	Items	Specifica	tions	Test Methods



7	Temperature Cycle	Appearance  Electrical specifications		No severe damages			Set the specimens to the supporting jig in the same manner and under the same condition as	
				Satisfy paragrap	-1	listed in	Fig.1 and conduct the 100 cycles according to the temperatures and time shown in the following table.	
				Step	1	2	2	
		Tem		p.(deg.C)	Min operating Temp. +0/-3		perating 	
			Tir	me (min)	30+/-3		+/-3	
8	Humidity Load Life	Appearance		No severe damages			Temperature : 85+/-2 deg.C Humidity : 80 to 85%RH	
		Electrical specifications		Satisfy specifications listed in paragraph 6.			Period : 500+24/-0 h Room Condition : 2 to 24 h Supply Voltage : 3.63V D.C. to V_I_O,	
	I Park Taran						1.93V D.C to BTRF_REG and BTL_REG	
9	High Temp. Load Life	Appearance		No severe damages			Temperature : 85+/-2 deg.C Period : 500+24/-0 h	
		Electrical specifications		Satisfy specifications listed in paragraph 6.		listed in	Room Condition: 2 to 24 h Supply Voltage: 3.63V D.C. to V_I_O 1.93V D.C to BTRF_REG and BTL_REG	

Excessive mechanical force or thermal stress may damage the products. Appropriate handling is required.

- 8. Interface UART
- 9. IC/Firmware BROADCOM's BCM2035 B3 Version
- 10. Production Site FUKUI MURATA MFG.CO.,LTD.



# Fig.1 <u>Measurement Board</u>

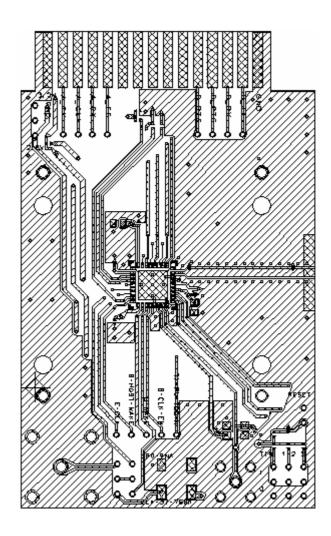
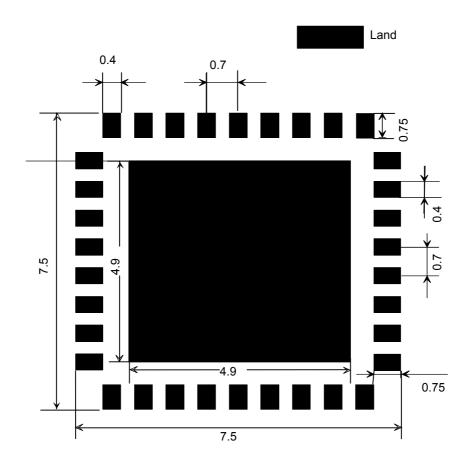




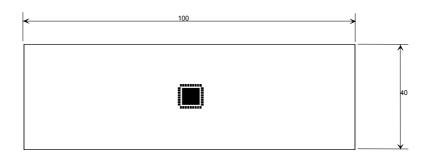
Fig.2 <u>Land Patterns</u>

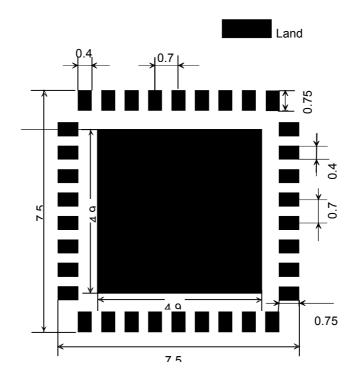


(Unit:mm)



Fig.2 <u>Testing Board</u>

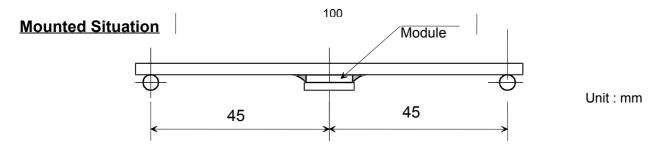


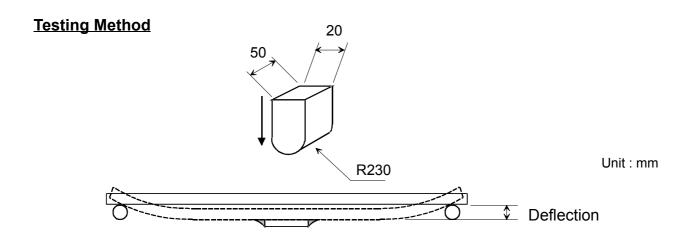


Unit:mm

Glass epoxy board t=0.8mm Copper thickness 35um min

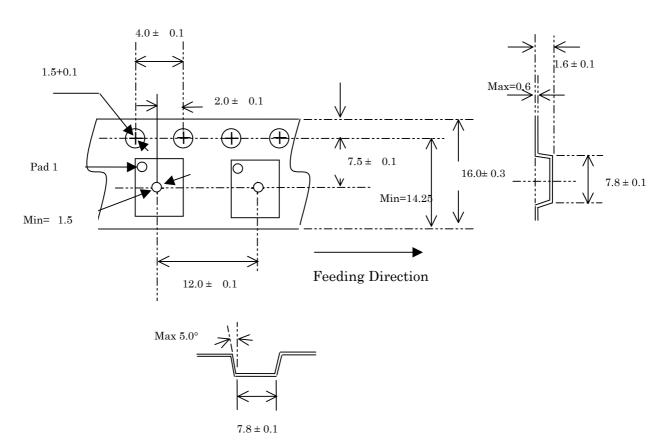




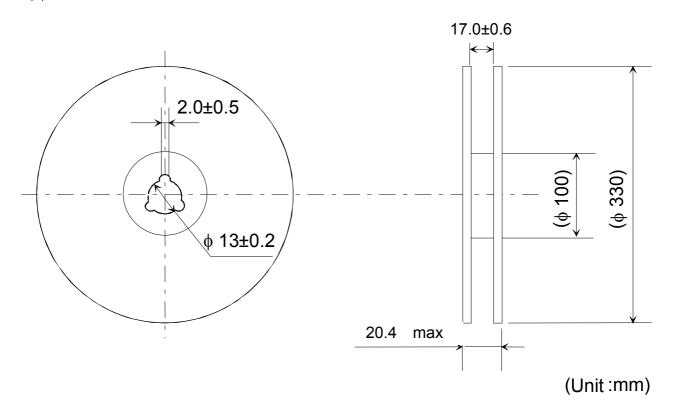




- 11. Tape and Reel Packing
- (1) Dimensions of Tape ( Plastic tape )
  1.Cumulative tolerance of max. ± 0.3 every 10 pitches
  - 2.Reference value

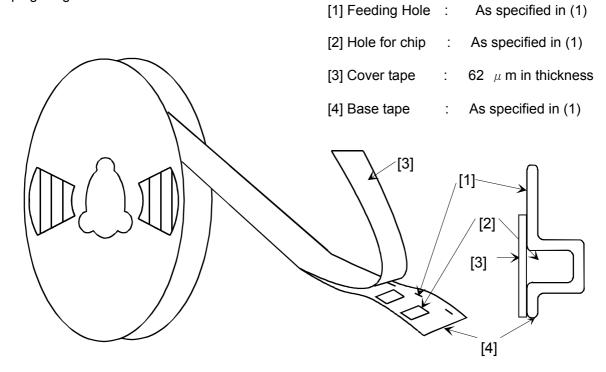


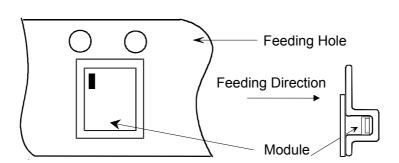
# (2) Dimensions of Reel





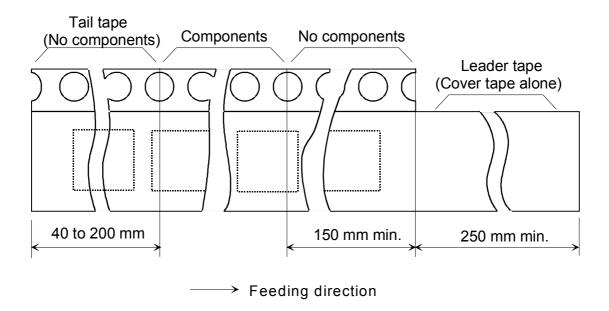
# (3) Taping Diagrams







# (4) Leader and Tail tape

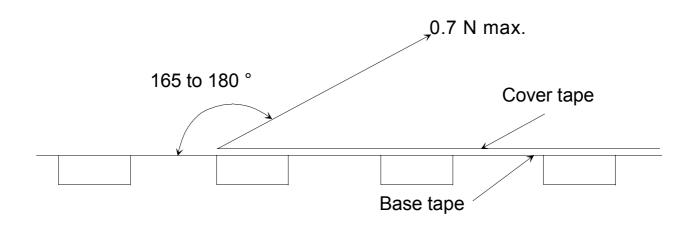


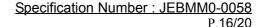
- (5) The tape for chips are wound clockwise, the feeding holes to the right side as the tape is pulled toward the user.
- (6) The cover tape and base tape are not adhered at no components area for 250 mm min.
- (7) Tear off strength against pulling of cover tape : 5 N min.
- (8) Packaging unit: 1000 pcs./ reel
- (9) material : Base tape : Plastic

Reel : Plastic

Cover tape, cavity tape and reel are made the anti-static processing.

(10) Peeling of force: 0.7 N max. in the direction of peeling as shown below.







#### NOTICE

## 1. Storage Conditions:

The product shall be stored under the following conditions in order not to damage the solderbility of the external electrodes.

- The product shall be stored without opening the packing and at the ambient temperature between 5 and 30 deg.C and humidity between 20 and 70 %RH. And the product shall be used within 6 months after reception. (Packing materials, in particular, may be deformed at the temperature over 45 deg.C.)
- After opening the packing, the product shall be stored at 5 to 30 deg.C /  $\leq$  60 %RH and the product shall be used within 48 hours. If the product is not used within 48 hours after opening the packing, the product shall be baked under the following conditions.

Baking condition: 125 +/-5 deg.C, 24 hours, 1 time

The products shall be baked on the heat-resistant tray because the material (Base Tape, Reel Tape and Cover Tape) are not heat-resistant.

- The product shall be stored in non corrosive gas (Cl<sub>2</sub>, NH<sub>3</sub>, SO<sub>2</sub>, No<sub>x</sub>, etc.).
- Solderbility shall be confirmed before use if the product is stored for more than 3 months.
- When the indicator in the packing has changed its color, the product shall be baked before soldering.
- Any excess mechanical shock including, but not limited to, sticking the packing materials by sharp object and dropping the product, shall not be applied in order not to damage the packing materials.

### 2. Handling Conditions:

- Be careful in handling or transporting products because excessive stress or mechanical shock may break products due to the nature of ceramics structure.
- Handle with care because the characteristics of products may change if products may have cracks or damages on their terminals. Do not touch products with bear hands that may result in poor solderability.

# 3. Standard PCB Design (Land Patterns and Dimensions) :

- All the ground terminals should be connected to the ground patterns. Please refer to Fig.2 for the standard land dimensions.
- The recommended land patterns and dimensions are as Murata's standard. The characteristics of products may vary depending on the pattern drawing method, grounding method, land dimensions, land forming method of the NC terminals and the PCB material and thickness. Therefore, be sure to verify the characteristics in the actual set. When using non-standard lands, contact Murata beforehand.

## 4. Notice for Chip Placer:

- When placing products on the PCB, products may be stressed and broken by uneven forces from a worn-out chucking locating claw or a suction nozzle. To prevent products from damages, be sure to follow the specifications for the maintenance of the chip placer being used. For the positioning of products on the PCB, be aware that mechanical chucking may damage products.



# 5. Soldering Conditions:

- Carefully perform preheating so that the temperature difference (delta T) between the solder and products surface should be in the following range. When products are immersed in solvent after mounting, pay special attention to maintain the temperature difference within 100 deg.C. Soldering must be carried out by the above mentioned conditions to prevent products from damage. Contact Murata before use if concerning other soldering conditions.

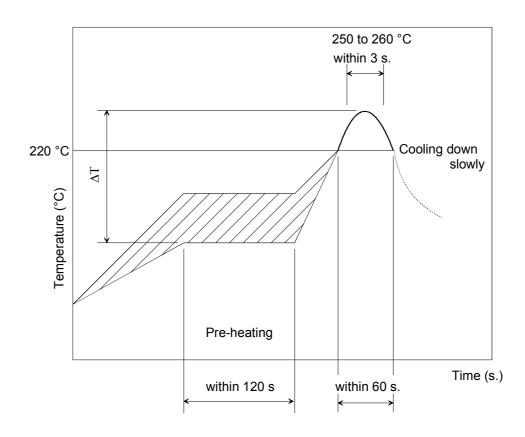
Soldering methods	Temperature	
Soldering iron method	dolto T < 120 dog C	
Reflow method	delta T <u>≤</u> 130 deg.C	

- Soldering iron method conditions are indicated below.

Kind of iron Items	Ceramic heater
Soldering iron wattage	<u>≤</u> 18 W
Temperature of iron-tip	<u>≤</u> 350 °C
Iron contact time	within 3 s

- Diameter of iron-tip :  $\phi$  3.0 mm max.
- Do not touch the module itself directly by the iron-tip.

# Reflow soldering standard conditions(Example)



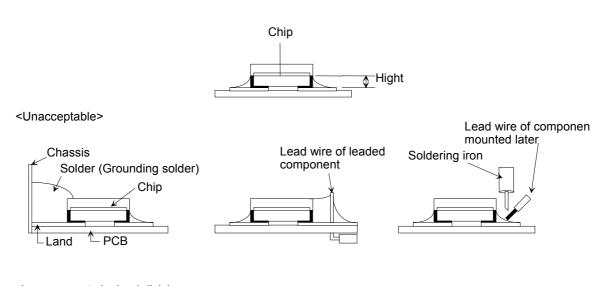


- Use rosin type flux or weakly active flux with a chlorine content of 0.2 wt% or less. Be careful so as not to remain the flux residue around products. Because there are possibilities to become worse the characteristics.

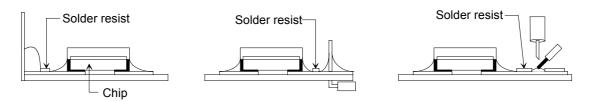
## - Amount of Solder Paste:

Ensure that solder is applied smoothly to a minimum height of 0.2 to 0.5 mm at the end surface of the external electrodes. If too much or little solder is applied, there is high possibility that the mechanical strength will be insufficient, creating the variation of characteristics.

# Amount of solder paste



# <Improvements by land division>





## 6. Operational Environment Conditions:

- Products are designed to work for electronic products under normal environmental conditions (ambient temperature, humidity and pressure). Therefore, products have no problems to be used under the similar conditions to the above-mentioned. However, if products are used under the following circumstances, it may damage products and electric shock and abnormal temperature may occur.
  - In an atmosphere containing corrosive gas (CL<sub>2</sub>, NH<sub>3</sub>, SO<sub>x</sub>, NO<sub>x</sub>, etc.).
  - In an atmosphere containing combustible and volatile gases.
  - Dusty place.
  - Direct sunlight place.
  - Water splashing place.
  - Humid place where water condenses.
  - Freezing place.
- If there are possibilities for products to be used under the preceding clause, consult with Murata before actual use.
- As it might be a cause of degradation or destruction to apply static electricity to products, do not apply static electricity or excessive voltage while assembling and measuring.

# 7. Limitation of Applications:

Please contact Murata before using products for the applications listed below which require especially high reliability for the prevention of defects which might directly cause damage to the third party's life, body or property.

- Aircraft equipment.
- Aerospace equipment.
- Undersea equipment.
- Medical equipment.
- Transportation equipment (vehicles, trains, ships, etc.).
- Traffic signal equipment.
- Disaster prevention / crime prevention equipment.
- Data-processing equipment
- Application of similar complexity and/ or reliability requirements to the applications listed in the above.

Specification Number : JEBMM0-0058 P.20/20





# Note:

- Please make sure that your product has been evaluated and confirmed against your specifications when our product is mounted to your product.
- All the items and parameters in this product specification have been prescribed on the premise that our product is used for the purpose, under the condition and in the environment agreed upon between you and us. You are requested not to use our product deviating from such agreement.
- We consider it not appropriate to include other terms and conditions for transaction warranty in product specifications, drawings or other technical documents. Therefore, even if your original part of this product specification includes such terms and conditions as warranty clause, product liability clause, or intellectual property infringement liability clause, we are not able to accept such terms and conditions in this product specification unless they are based on the governmental regulation or what we have agreed otherwise in a separate contact. We would like to suggest that you propose to discuss them under negotiation of contract.